Diode Semiconductor Device - Page 1 of 1



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Incl	losure Material:
Cer	amic
Ove	erall Length:
1.12	20 inches
Ter	minal Length:
0.25	50 inches
Ove	erall Diameter:
0.45	50 inches
Μοι	unting Method:
Terr	minal
Fea	tures Provided:
Her	metically sealed case
Sen	niconductor Material:
Silic	con
Vol	tage Rating In Volts Per Characteristic:
200	.0 reverse voltage, peak
Cur	rent Rating Per Characteristic:
1.50	amperes forward current, average absolute
Max	ximum Operating Tempurature Per Measurement Point:
150	0.0 degrees celsius ambient air
Ter	minal Type And Quantity:
2 fe	rrule
She	elf Life:
N/a	
Uni	t Of Measure:
Den	nilitarization:
No	
Fiig	j:
A11	0a0